

Search by part # or keyword

Parametric Search | MyMicrosemi Login

Products | Applications | Design Tools | Ordering | Services & Support | Company

Power Matters.

Home > 2N3621 (#23115)

## **Product Status** 2N3621 (#23115) **Products** Obsolete **Related Links** Product Directory **Overview Diagrams** Technical support Applications How to Buy Parametric Search Available Stock Sales Contacts Electrical Rating Symbo Max Unit Collector to Emitter Saturation Voltage V<sub>CE(sat)</sub> 0.75 V DC Current Gain HFE 40.00 Maximum Electrical Rating Symbol Max Unit Breakdown Voltage, Collector-Base (Emitter Open) 75.00 V V<sub>BR(CBO)</sub> 5.00 А Collector Current (dc) $I_{C}$ 40.00 V Collector-Emitter Voltage (Base Open) V<sub>CEO</sub> V<sub>EBO</sub> 4.00 V Emitter-Base Voltage (Collector Open) Power Dissipation, Total Pт 30.00 W This part can be found in the following product categories: Power Discretes & Modules > BJT( BiPolar Junction Transistor) > PNP Transistor Products | Applications | Company | Careers | Investors | Survey | Privacy Policy | Terms & Conditions | Product Disclaimer | Terms of Use Copyright © 2016 Microsemi Corporation. All rights reserved. The Microsemi logo is a registered trademark of Microsemi Corporation.